# **Diodes**

### **Structure. Symbol**

## **Physical structure** Diode - semiconductor device



The *pn* **junction** - an interface between two types of semiconductor materials, *p*-type and *n*-type.

In the outer shells of the electrically neutral atoms:

- o the *p* (positive) side contains an excess of holes (positive charges)
- o the *n* (negative) side contains an excess of electrons (negative charges)

The *pn* junction is created by **doping**:

- $\checkmark$  p-type doping an intrinsic semiconductor (e.g. Si) is doped with acceptor impurities (column 3 in the periodic table  $\rightarrow$  excess of holes
- ✓ *n*-type doping an intrinsic semiconductor (e.g. Si) is doped with donor impurities (column 5 in the periodic table  $\rightarrow$  excess of electrons

A *pn* junction diode allows electric charges to flow only in one direction:

- negative charges (electrons) can flow through the junction from *n* to *p* but not from *p* to *n*,
- o positive charges (holes) can flow through the junction from *p* to *n* but not from *n* to *p*,



When the *pn* junction is forward-biased, electric charge flows freely due to reduced resistance of the *pn* junction.

When the p–n junction is reverse-biased, the junction barrier (and therefore resistance) becomes greater and charge flow is minimal (zero).



#### Circuit symbol

Positive directions for current and voltage





The arrow in the diode's symbol points in the direction of forward current flow.

### **Current – voltage characteristic**

The current flowing through the diode is controlled by the voltage drop across the diode itself – **nonlinear semiconductor device**

Shockley diode equation (diffusion equation)

$$
i_D = I_S(e^{nV_T} - 1) \approx I_S e^{nV_T}
$$

 $I_S$  - saturation current (~ nA - pA) *depends on temperature*

 $i_D$  depends exponentialy on  $v<sub>D</sub>$ 

*q*  $V_T = \frac{KT}{T}$  $=\frac{\mathbf{M}}{2}$  thermal voltage (*depends on temperature*)

*K -* Boltzmann's constant

- $V_T = 25 \text{mV}$  @  $20^{\text{o}} \text{C}$
- *q –* elementary charge (electric charge carried by a single electron)
- *T –* absolute temperature measured in K degrees

*n – ideality factor (emission coefficient)*

- $n = 2$  discrete diodes
- $n = 1$  integrated diodes



#### **Illustration**

![](_page_6_Figure_1.jpeg)

*D* is a rectifier diode, 1N400x with  $I_s$ =14nA,  $n = 2$ 

Assuming a voltage drop across the diode in conduction

 $v_D = 0.7V = 700$  mV

$$
V_T = 25 \text{mV} \quad \textcircled{a} \quad 20^{\circ} \text{C}
$$

the current through the diode results as:

$$
i_D = 14.10^{-9} \cdot e^{\frac{700}{2 \cdot 25}} = 16.8 \text{mA}
$$

#### **Operating (quiescent) point**  $\mathcal{Q}(V_{D}; I_{D})$

Illustration for  $1N400x$  with  $I_s=14nA$ ,  $n=2$ 

![](_page_7_Figure_2.jpeg)

### **Temperature dependence**

*T*

*D*

*nV*

 $V_{D2}$   $V_{D1}$ 

 $D - S$  $i_{\scriptscriptstyle{D}} \cong I_{\scriptscriptstyle{E}}e$  *v*

![](_page_8_Figure_1.jpeg)

At a constant current the voltage across the diode decreases by approximately 2 mV for every  $1^{\circ}$ C increase in temperature.

#### **Negative tempco**

$$
TC = -2mV / {}^{o}C
$$

 $20^{\circ}$  C  $v_D = 650 \,\text{mV}$ 

 $40^{\circ}$  C  $v_{\rm D} = 610 \,\rm mV$ 

$$
v_D(T_2) = v_D(T_1) + TC \cdot (T_2 - T_1)|_{I_D - cst}
$$

**At a constant voltage** across the diode the current increases with the temperature

 $T_2 > T_1$ 

### **Determining the operating point**

❑ Circuit with a dc voltage source and a resistor

![](_page_9_Figure_2.jpeg)

Transcendental equation

**Two solving methods:**

- **1. Graphical method**
- 

![](_page_10_Figure_0.jpeg)

### **Numerical analysis - simplified**

If  $V_I$  high enough, the *D* is on; (else *D* is off)

Assume the voltage drop across the conducting diode  $V_D = 0.7V$ and compute the current  $I_D$  using the load line (circuit) equation

 $V_I = I_D R + V_D$ 

![](_page_11_Figure_4.jpeg)

#### **Illustration**

![](_page_12_Figure_1.jpeg)

 $V_I = 9V$ ,  $R = 0.5K\Omega$ 

a) What is the operating (quiescent) point of the diode *D*?

*Q*(0.7V, 16.6mA)

 $D$  – (on)

 $V_D$  high enough

Assume = $V_D = 0.7V$  across the conducting diode

$$
I_D = \frac{V_I - V_D}{R}
$$
  $I_D = \frac{9 - 0.7}{0.5} = 16.6 \text{ mA}$ 

### **Numerical analysis - iteratively**

**1. Consider** an initial value of diode voltage, eg.  $V_D^{(0)} = 0.7V$ and **compute** the current  $I_D^{(0)}$  using the load line equation.

 $(V_{D}^{(0)}, I_{D}^{(0)})$  – **initial solution** 

**2.** With *I<sup>D</sup>* (0) compute the diode voltage from **diode equation**, then the current  $\boldsymbol{I_D}^{(1)}$  from load line equation

 $(\boldsymbol{V_D}^{(1)}, \boldsymbol{I_D}^{(1)})$  – solution after first iteration

We finalize one iteration. If a more accurate solution is necessary, further iteration should be performed.

**For quick, first order analysis of the circuit, usually the initial solution is considered!**

### **Illustration**

![](_page_14_Figure_1.jpeg)

![](_page_14_Picture_2.jpeg)

Consider  $V_f$ =3V,  $R$ =0.5K $\Omega$ ,  $D$  is 1N400x with  $I_s$ =14nA and *n*=2. What is the operating (quiescent) point of the diode**?**

#### **Quick, first order analysis:**

 $V_D > 0.6V$  *D* – (on)

Assume  $V_D = 0.7V$  in conduction

$$
I_D = \frac{V_I - V_D}{R}
$$
  $I_D = \frac{3 - 0.7}{0.5} = 4.6 \text{ mA}$   $Q(0.7 \text{ V}, 4.6 \text{ mA})$ 

**Detailed analysis:** 

$$
I_D = \frac{V_I - V_D}{R} \qquad V_D = nV_T \ln \frac{I_D}{I_S}
$$
  

$$
V_D^{(0)} = 0.7 \text{V}
$$

OPTIONAL

$$
I_D^{(0)} = \frac{3 - 0.7}{0.5} = 4.6 \text{ mA}
$$
  $Q^{(0)}(0.7 \text{V}, 4.6 \text{mA})$ 

$$
V_D^{(1)} = nV_T \cdot \ln \frac{I_D^{(0)}}{I_S} = 2 \cdot 0.025 \cdot \ln \frac{4.6 \text{ mA}}{14 \text{ nA}} = 0.635 \text{V}
$$
  

$$
I_D^{(1)} = \frac{V_I - V_D^{(1)}}{R} = \frac{3 - 0.635}{0.5} = 4.73 \text{ mA}
$$
  $Q^{(1)}(0.635 \text{V}, 4.73 \text{ mA})$ 

$$
V_D^{(2)} = n \cdot V_T \cdot \ln \frac{I_D^{(1)}}{I_S} = 2 \cdot 0.025 \cdot \ln \frac{4.73 \text{ mA}}{14 \text{ nA}} = 0.637 \text{ V}
$$
  

$$
I_D^{(2)} = \frac{V_I - V_D^{(2)}}{R} = \frac{3 - 0.637}{0.5} = 4.726 \text{ mA}
$$
  

$$
Q^{(2)}(0.637 \text{ V}, 4.726 \text{ mA})
$$

![](_page_16_Figure_0.jpeg)

**If**  $v_D < 0.7V$   $D - (off)$  **If**  $v_D$  tends to be  $> 0.7V$   $D - (on)$ 

![](_page_16_Figure_2.jpeg)

 $v_D < 0.7V$  $i_D = 0$ 

![](_page_16_Figure_4.jpeg)

 $v_D = 0.7V$  $i_D > 0$ 

### **DR two-port networks analysis**

![](_page_17_Figure_1.jpeg)

#### *VTC* **– voltage transfer characteristic**

- 1. Consider **all possible situations** resulting from the combination of the **diode states (***on***,** *off***)**
- 2. For each situation :
	- i. draw the equivalent circuit
	- ii. find  $v<sub>O</sub>$
	- iii. determine the range of  $v_I$  for that particular situation
- 3. Draw *VTC.*

### **Example**

### What is the VTC  $v_o(v_l)$ ?

![](_page_18_Figure_2.jpeg)

### **Example - cont**

What is the VTC  $v_O(v_I)$ ?

![](_page_19_Figure_2.jpeg)

![](_page_19_Figure_3.jpeg)

$$
v_D < 0.7 \quad \text{if} \quad i_D = 0
$$
\n
$$
\mathcal{V}_O = 0
$$

$$
D - (on)
$$
\n
$$
d
$$
\n
$$
v_I \downarrow \qquad v_D
$$
\n
$$
= 0
$$
\n
$$
i_D > 0 \quad v_D = 0.7 V
$$
\n
$$
v_O = v_I - v_D = v_I - 0.7 V
$$

$$
\frac{v_D = v_I - v_O}{v_I < 0.7 \text{V}} \qquad \qquad i_D = \frac{v_O}{R} = \frac{v_I - 0.7 \text{V}}{R} \qquad \boxed{v_I > 0.7 \text{V}}
$$

![](_page_20_Figure_0.jpeg)

#### **Waveforms for a voltage rectifier**

![](_page_21_Figure_1.jpeg)

![](_page_21_Figure_2.jpeg)

 $v_o(t) = ?$ 

#### **Waveforms for a voltage rectifier**

![](_page_22_Figure_1.jpeg)

![](_page_22_Figure_2.jpeg)

### **The influence of the threshold voltage and voltage drop across the diode in conduction**

![](_page_23_Figure_1.jpeg)

 $\cdot \cdot$  If the input voltage is large enough ( $\gg 0.7V$ )

- the threshold voltage can be neglected (considered 0V)
- the voltage drop across the conducting diode can be neglected;  $D - (on); v_0 = v_I$

### **Applications of** *DR* **two-port networks**

#### ❖ **Half-wave rectifier**

![](_page_24_Figure_2.jpeg)

13.4

The difference in voltage between the primary and the secondary windings is achieved by changing the number of coil turns in the primary winding compared to the number of coil turns on the secondary winding.

![](_page_25_Picture_0.jpeg)

![](_page_25_Picture_1.jpeg)

![](_page_25_Figure_2.jpeg)

![](_page_25_Figure_3.jpeg)

![](_page_26_Figure_0.jpeg)

![](_page_26_Figure_1.jpeg)

![](_page_27_Figure_0.jpeg)

$$
\begin{cases} v_A & D_1 - (on), \ D_2 - (off); \quad v_0 = v_A - 0.7 \text{V} \\ v_A > 0.7 \text{V} \end{cases}
$$

$$
\begin{cases} v_B > v_A & D_1 - (off), \ D_2 - (on); \quad v_O = v_B - 0.7 \text{V} \\ v_B > 0.7 \text{V} & \end{cases}
$$

 $D_{\rm 1}$  $-$  (*off* ),  $\, D_{2}$  $(v(f); v$ <sub>O</sub>  $= 0$ = $v<sub>o</sub> = \max(v<sub>A</sub> - 0.7V; v<sub>B</sub> - 0.7V; 0V)$  $\bigg($  $\bigg\{$  $\int$  $\lt$  $\lt$ 0.7V 0.7V *B A v v*

![](_page_28_Figure_0.jpeg)

$$
v_O = \max(v_A - 0.7V; v_B - 0.7V; 0)
$$
  
 $v_O = \max(v_A; v_B; 0)$  neglecting 0.7V

neglecting 0.7V  $D$  – constant-voltage-drop

What is the peak value of the current through each circuit element if *R*=5kΩ?

What is the range of values for *R,* if the peak forward current through diode is 200mA?

![](_page_28_Figure_5.jpeg)

![](_page_29_Figure_0.jpeg)

### **DR logic circuits**

#### analog signal digital signal

![](_page_30_Figure_2.jpeg)

### ❖ **two-input OR circuit**

![](_page_31_Figure_1.jpeg)

 $0V \rightarrow$  logic 0  $5V \rightarrow$  logic 1

![](_page_31_Picture_82.jpeg)

 $\, B \,$ Y А 0 0 0  $\theta$ 1 1  $\mathbf 1$  $\overline{0}$ 1  $\mathbf{1}$ 1

operating table truth table

### ❖ **three-input AND circuit**

 $0V \rightarrow$  logic 0  $5V \rightarrow$  logic 1

![](_page_32_Figure_2.jpeg)

![](_page_32_Picture_77.jpeg)

operating table truth table

❖ Full wave rectifier - diode bridge

neglecting 0.7V across the conducting diode

![](_page_33_Figure_2.jpeg)

 $v_I > 0$ V  $v_I < 0$ V

![](_page_33_Figure_3.jpeg)

 $\triangleright$  positive half,  $v_I > 0$  $D_1, D_3$  – (on)  $D_2, D_4$  – (off)

> $\triangleright$  negative half,  $v_I < 0$  $D_1$ ,  $D_3$  – (off)  $D_2$ ,  $D_4$  – (on)

![](_page_34_Figure_0.jpeg)

#### Problem

![](_page_35_Figure_1.jpeg)

For the circuit in the figure,  $R_L$ =50Ω. Assume  $\hat{V}_R$  $I_{I} = 25V$ 

- a)  $v_o(t)$  and  $i_o(t)$
- b) What are the value of the maximum reverse voltage  $v_{DR}$  across each diode and the maximum forward current through each diode?
- c) Repeat a) and b) assuming  $\hat{V}_i$  $I_I = 6.4V$

### **Power-supply filtering**

 $v_I$  is the voltage in a secondary winding of a step-down line transformer.

It is required to obtain an almost dc voltage (on a load resistor)

![](_page_36_Figure_3.jpeg)

How "to smooth" the output voltage (as close as possible to dc)?

### **Power-supply filtering - cont.**

1st step

Half-wave (full wave) rectifier

![](_page_37_Figure_3.jpeg)

How "to smooth" the output voltage (as close as possible to dc)?

![](_page_38_Figure_0.jpeg)

Between successive peeks of input voltage (and rectified voltage),  $D - \textit{off}$ , the capacitor acts as a element of electrical energy storage, providing electrical energy in the load, with a decrease of its own voltage.

![](_page_39_Figure_0.jpeg)

If the **current** through the capacitor, can be approximated as being a **constant** one  $I_c$ :

$$
v_{c(t)} = \frac{1}{C}I_c(t - t_0) + v_c(t_0)
$$

$$
v_{c(t)} - v_c(t_0) = \frac{1}{C}I_c(t - t_0)
$$

$$
\Delta v_c = \frac{1}{C}I_c\Delta t
$$

$$
Cdv_c(t) = i_c(t)dt
$$
 for  $I_c$  constant

![](_page_40_Figure_0.jpeg)

Between successive peeks of input voltage (and rectified voltage), **D -** *off*, the capacitor acts as a element of electrical energy storage, providing electrical energy in the load, with a decrease of its own voltage:

*C* discharges through *R;* the discharging current is supposed to be constant, to its maximum value.

$$
\Delta v_c = \frac{1}{C} I_c \Delta t
$$
  
\n
$$
I_c = \frac{\hat{v}_o}{R}
$$
  
\n
$$
\Delta t = t_d = T - t_c \approx T
$$
  
\n
$$
\Delta v_c = \Delta v = \frac{1}{C} I_c \Delta t = \frac{1}{C} \frac{\hat{V}_o}{R} T
$$
  
\n
$$
\Delta v = \hat{V}_o \frac{T}{RC} = \frac{1}{f} \frac{\hat{V}_o}{RC}
$$

*RC – time constant of the circuit*

#### **Example**

 $\hat{V}$  $P_I = 10.7V$   $f = 50 Hz$   $R_L = 100 \Omega$   $\Delta v < 1.5V$ *C***=?**

![](_page_41_Figure_2.jpeg)

We chose an electrolytic capacitor  $C = 1500 \mu F/25V$ What is the actual value of the output ripple? What should be a new value of *C* if the output ripple must be reduce to the half?

Solve again in the case of full-wave rectification.